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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-MBR3045CT-1PBF</u>

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VISHAY

Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VS-MBR3045CT-1PBF - DIODE ARRAY SCHOTTKY 45V TO262 Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



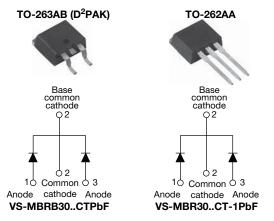


Vishay Semiconductors

COMPLIANT

HALOGEN

High Performance Schottky Rectifier, 2 x 15 A



PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	30 A
V _R	35 V, 45 V
V _F at I _F	0.6 V
I _{RM} max.	100 mA at 125 °C
T _J max.	150 °C
Diode variation	Single die
E _{AS}	10.0 mJ

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- Center tap D²PAK and TO-262 packages
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- strength and moisture resistance

 Guard ring for enhanced ruggedness and long term
- reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform (per device)	30	Λ.				
I _{FRM}	T _C = 123 °C (per leg)	30	A A				
V _{RRM}		35, 45	V				
I _{FSM}	t _p = 5 µs sine	1020	A				
V _F	20 A _{pk} , T _J = 125 °C	0.6	V				
T _J	Range	-65 to +150	°C				

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-MBRB3035CTPbF VS-MBRB3045CT-DbF VS-MBR3045CT-1PbF VS-MBR3045CT-1PbF UNITS						
Maximum DC reverse voltage	V_{R}	35	45	V		
Maximum working peak reverse voltage	V_{RWM}	33	45	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average per leg		T 100 °C material	W	15			
forward current per device	I _{F(AV)}	$I_C = 123$ °C, rated	$T_C = 123 ^{\circ}\text{C}$, rated V_R				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square	Rated V _R , square wave, 20 kHz, T _C = 123 °C				
Non-venetitive polycyma	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1020	Α		
Non-repetitive peak surge current		Surge applied at ra single phase, 60 H	200				
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2$	A, L = 5 mH	10	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying I Frequency limited	inearly to zero in 1 μ s by T _J maximum V _A = 1.5 x V _R typical	2	Α		

Revision: 15-Jul-14 **1** Document Number: 94310

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VS-MBRB30..CTPbF, VS-MBR30..CT-1PbF Series

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS			
		30 A	T _J = 25 °C	0.76			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	T 105 °C	0.6	V		
		30 A	T _J = 125 °C	0.72			
Maximum instantaneous	I _{RM} ⁽¹⁾	T _J = 25 °C	Data d DO coltana	1	mA		
reverse current	IRM (")	T _J = 125 °C	Rated DC voltage	100			
Threshold voltage	V _{F(TO)}	T T ma assismantina		0.29	V		
Forward slope resistance	r _t	ı j = ı j maxımum	$T_J = T_J$ maximum		mΩ		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal rar	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C				
Typical series inductance	L _S	Measured from top of ter	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 $\%\,$

THERMAL - MECH	IANICAL	SPECIFIC	ATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction tempe	rature range	TJ		-65 to +150	°C			
Maximum storage temper	rature range	T _{Stg}		-65 to +175				
Maximum thermal resista junction to case per leg	nce,	R _{thJC}	DC operation	1.5				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W			
Maximum thermal resista junction to ambient	nce,	R _{thJA}	DC operation	50				
Annuavimenta vuoimbt				2	g			
Approximate weight				0.07	OZ.			
May anting toward	minimum		New July winested through	6 (5)	kgf · cm			
Mounting torque maxim			Non-lubricated threads	12 (10)	(lbf · in)			
Madding davis			Case style D ² PAK	MBRB3	3045CT			
ivial Killy device	Marking device				Case style TO-262	MBR30	MBR3045CT-1	

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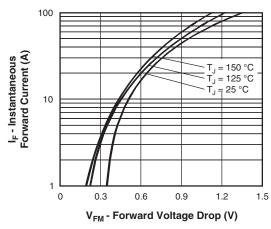


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

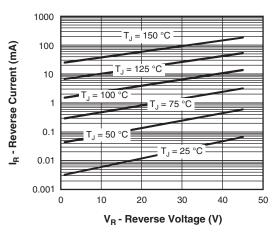


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

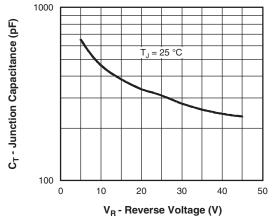


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

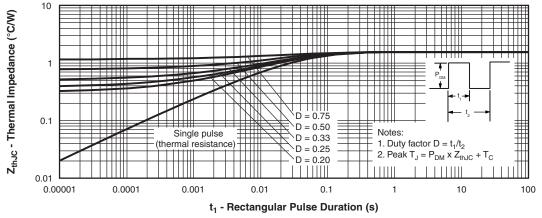


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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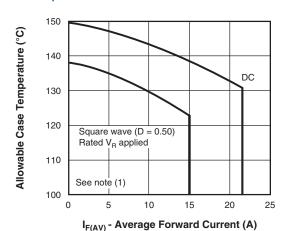


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

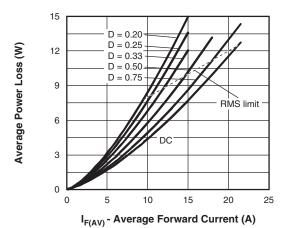


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

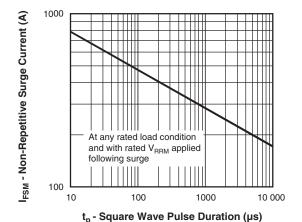


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$

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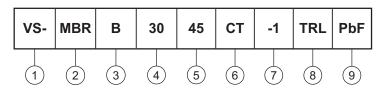
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ORDERING INFORMATION TABLE





Vishay Semiconductors product

Essential part number

• $B = D^2PAK$ **| 7** | None

• None = TO-262 **7**

Current rating (30 = 30 A)

35 = 35 V5 Voltage ratings 45 = 45 V

6 CT = essential part number

> • None = D^2PAK **3** = B • -1 = TO-262 3 None

8 • None = tube (50 pieces)

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 • PbF = lead (Pb)-free (for TO-262 and D²PAK tube)

• P = lead (Pb)-free (for D²PAK TRR and TRL)

LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?95014</u>							
www.vishay.com/doc?95008							
Packaging information <u>www.vishay.com/doc?95032</u>							



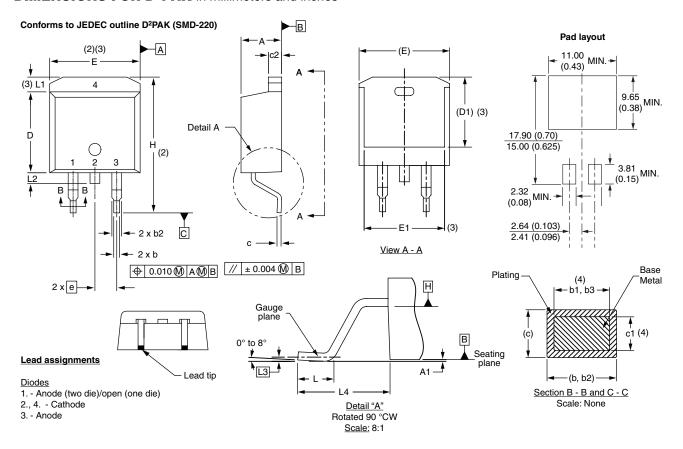


Outline Dimensions

Vishay High Power Products

D²PAK, **TO-262**

DIMENSIONS FOR D²PAK in millimeters and inches



SYMBOL MILLI	MILLIM	ETERS	INC	HES	NOTES		SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

Document Number: 95014 Revision: 31-Mar-09 For technical questions concerning discrete products, contact: diodes-tech@vishay.com
For technical questions concerning module products, contact: ind-modules@vishay.com

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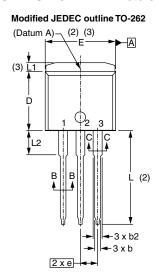
Outline Dimensions

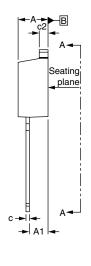
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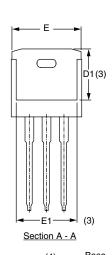
D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches







⊕ 0.010 A **M** B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode

Section B - B and C - C
Scale: None

b1, b3

metal

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.10) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

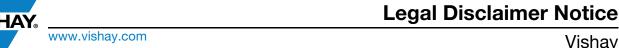
- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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